

SOT-23 Plastic-Encapsulate Diodes

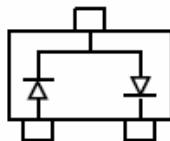
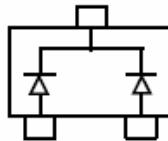
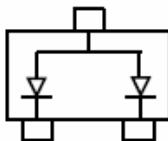
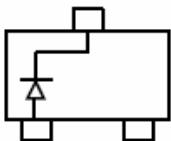
BAT54/A/C/S SCHOTTKY DIODES

FEATURES

Power Dissipation

PD : 200 mW (Tamb=25°C)

SOT-23



BAT54 MARKING: KL1 BAT54A MARKING: KL2 BAT54C MARKING: KL3 BAT54S MARKING: KL4

Maximum Ratings @TA=25

Parameter	Symbol	Limits			Unit
Peak Repetitive Peak reverse voltage	V _{RRM}				
Working Peak Reverse Voltage	V _{RWM}	30			V
DC Blocking Voltage	V _R				
Forward Continuous Current	I _{FM}	200			mA
Power Dissipation	Pd	200			mW
Storage temperature	T _{STG}	-55-150			°C

Electrical Characteristics@TA=25°C

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Reverse Breakdown Voltage	V _{(BR)R}	30			V	IR=100μA
Forward voltage	V _{F1}			0.24	V	I _F =0.1mA
	V _{F2}			0.32	V	I _F =1mA
	V _{F3}			0.40	V	I _F =10mA
	V _{F4}			0.50	V	I _F =30mA
	V _{F5}			1	V	I _F =100mA
Reverse current	I _R			2	μA	V _R =25V
Diode Capacitance	C _D			10	pF	V _R =1V,f=1MHz
Reverse Recovery Time	t _{rr}			5	nS	I _F =I _R =10mA I _{rr} =0.1XI _R ,R _L =100Ω

Typical Characteristics

BAT54/A/C/S

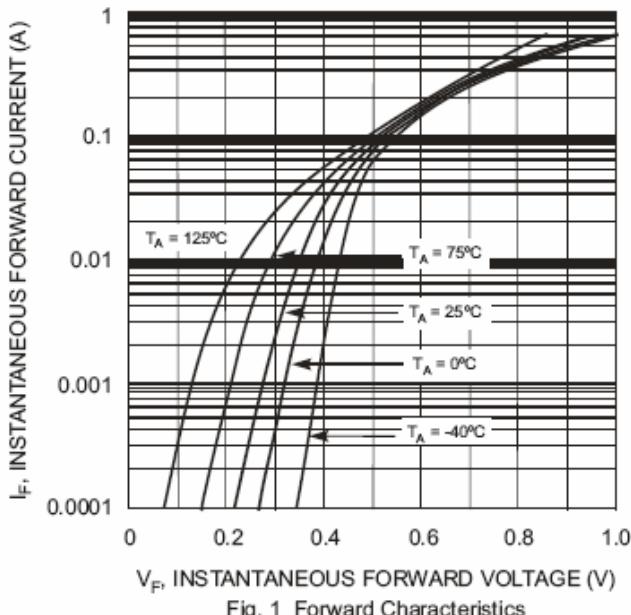


Fig. 1 Forward Characteristics

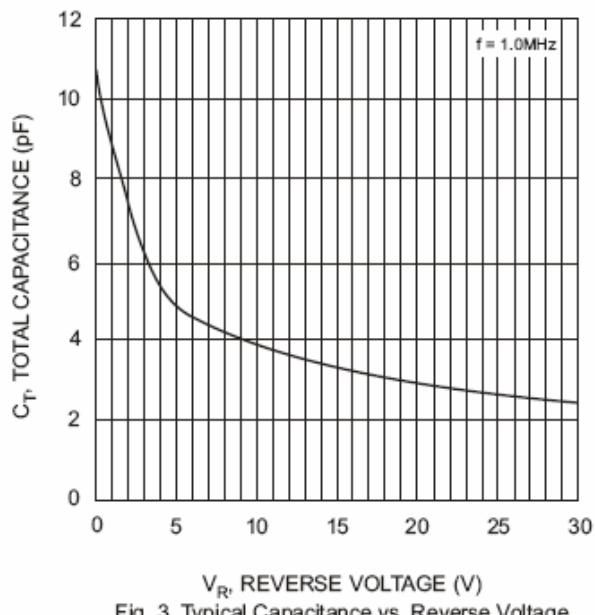


Fig. 3 Typical Capacitance vs. Reverse Voltage

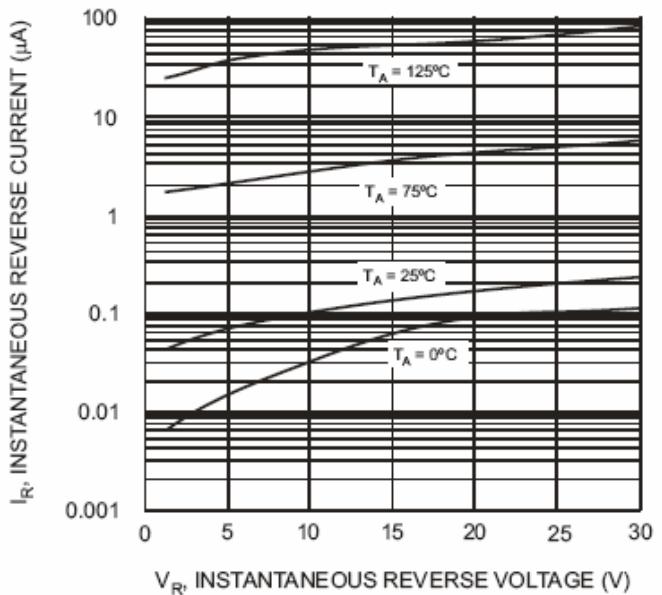


Fig. 2 Typical Reverse Characteristics

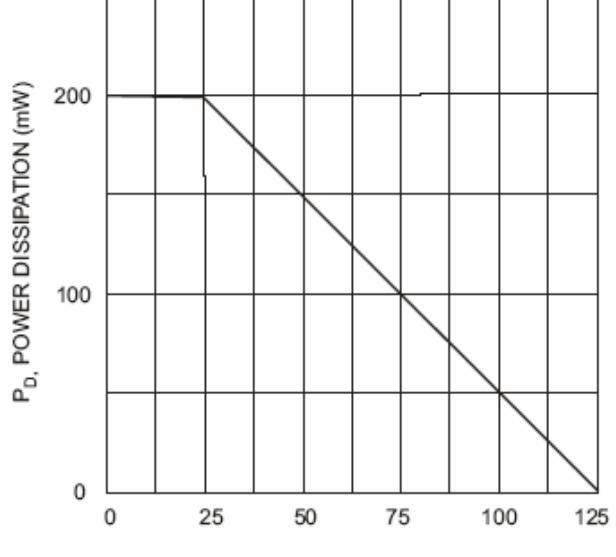


Fig. 4 Power Derating Curve